

74AUP2G02

Low-power dual 2-input NOR gate

Rev. 03 — 11 December 2008

Product data sheet

1. General description

The 74AUP2G02 provides a dual 2-input NOR function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

2. Features

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114E Class 3A exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | Version |
|-------------|-------------------|--------|--|--|----------|
| | Temperature range | Name | Description | | |
| 74AUP2G02DC | −40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | | SOT765-1 |
| 74AUP2G02GT | −40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | | SOT833-1 |
| 74AUP2G02GD | −40 °C to +125 °C | XSON8U | plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body 3 × 2 × 0.5 mm | | SOT996-2 |
| 74AUP2G02GM | −40 °C to +125 °C | XQFN8U | plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body 1.6 × 1.6 × 0.5 mm | | SOT902-1 |

4. Marking

Table 2. Marking codes

| Type number | Marking code |
|-------------|--------------|
| 74AUP2G02DC | p02 |
| 74AUP2G02GT | p02 |
| 74AUP2G02GD | p02 |
| 74AUP2G02GM | p02 |

5. Functional diagram

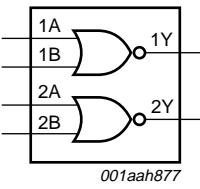


Fig 1. Logic symbol

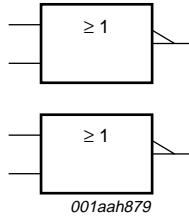


Fig 2. IEC logic symbol

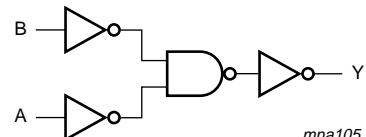


Fig 3. Logic diagram

6. Pinning information

6.1 Pinning

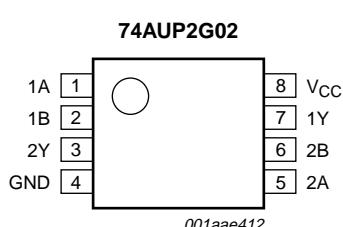
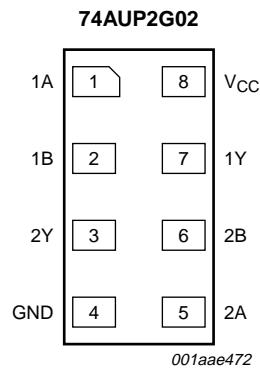
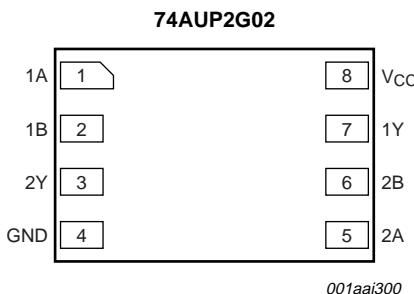


Fig 4. Pin configuration SOT765-1 (VSSOP8)



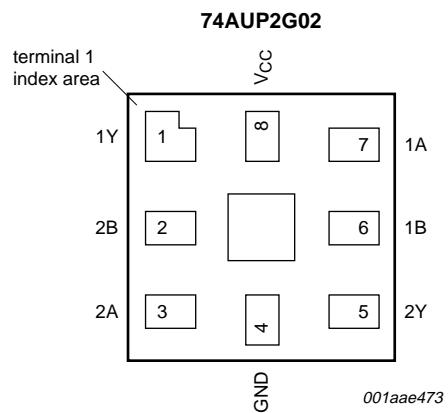
Transparent top view

Fig 5. Pin configuration SOT833-1 (XSON8)



Transparent top view

Fig 6. Pin configuration SOT996-2 (XSON8U)



Transparent top view

Fig 7. Pin configuration SOT902-1 (XQFN8U)

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | | Description |
|-----------------|---------------------------------|------|----------------|
| | SOT765-1, SOT833-1 and SOT996-2 | | |
| 1A, 2A | 1, 5 | 7, 3 | data input |
| 1B, 2B | 2, 6 | 6, 2 | data input |
| GND | 4 | 4 | ground (0 V) |
| 1Y, 2Y | 7, 3 | 1, 5 | data output |
| V _{CC} | 8 | 8 | supply voltage |

7. Functional description

Table 4. Function table^[1]

| Input | | Output |
|-------|----|--------|
| nA | nB | nY |
| L | L | H |
| L | H | L |
| H | L | L |
| H | H | L |

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|---------------------|------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | - | -50 | mA |
| V _I | input voltage | | ^[1] -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| V _O | output voltage | Active mode and Power-down mode | ^[1] -0.5 | +4.6 | V |
| I _O | output current | V _O = 0 V to V _{CC} | - | ±20 | mA |
| I _{CC} | supply current | | - | +50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | ^[2] - | 250 | mW |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K.

For XSON8, XSON8U and XQFN8U packages: above 45 °C the value of P_{tot} derates linearly with 2.4 mW/K.

9. Recommended operating conditions

Table 6. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|--|-----|-----------------|------|
| V _{CC} | supply voltage | | 0.8 | 3.6 | V |
| V _I | input voltage | | 0 | 3.6 | V |
| V _O | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V _{CC} = 0 V | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 0.8 V to 3.6 V | 0 | 200 | ns/V |

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| T_{amb} = 25 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.75 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.11 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.32 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 2.05 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.72 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.31 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.1 | µA |
| | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.2 | µA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.2 | µA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 0.5 | µA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V | [1] | - | 40 | µA |
| C _I | input capacitance | V _{CC} = 0 V to 3.6 V; V _I = GND or V _{CC} | - | 0.8 | - | pF |
| C _O | output capacitance | V _O = GND; V _{CC} = 0 V | - | 1.7 | - | pF |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--------------------------------------|---|------------------------|-----|------------------------|------|
| T_{amb} = -40 °C to +85 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.65 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.7 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.03 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.30 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.97 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.85 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.67 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.55 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.33 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.45 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | µA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.5 | µA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.6 | µA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 0.9 | µA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V | [1] | - | 50 | µA |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--------------------------------------|---|------------------------|-----|------------------------|------|
| T_{amb} = -40 °C to +125 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.75 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.25 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.6 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.30 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.50 | V |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.75 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.75 | μA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.75 | μA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 1.4 | μA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V | [1] | - | 75 | μA |

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristicsVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | T _{amb} = 25 °C | | | T _{amb} = -40 °C to +125 °C | | | Unit |
|------------------------------|-------------------|--|--------------------------|--------------------|------|--------------------------------------|-------------|--------------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| C_L = 5 pF | | | | | | | | | |
| t _{pd} | propagation delay | nA, nB to nY; see Figure 8 | [2] | | | | | | |
| | | V _{CC} = 0.8 V | - | 17.0 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.5 | 5.1 | 10.8 | 2.1 | 12.1 | 13.4 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 1.6 | 3.7 | 6.7 | 1.4 | 7.8 | 8.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.3 | 3.0 | 5.3 | 1.1 | 6.2 | 6.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.0 | 2.4 | 3.9 | 0.9 | 4.6 | 5.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.2 | 3.4 | 0.8 | 4.0 | 4.4 | ns |
| C_L = 10 pF | | | | | | | | | |
| t _{pd} | propagation delay | nA, nB to nY; see Figure 8 | [2] | | | | | | |
| | | V _{CC} = 0.8 V | - | 20.4 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.4 | 6.0 | 12.8 | 2.2 | 14.3 | 15.8 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 1.9 | 4.3 | 7.9 | 1.7 | 9.2 | 10.2 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.6 | 3.6 | 6.2 | 1.5 | 7.3 | 8.1 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.4 | 3.0 | 4.7 | 1.2 | 5.6 | 6.2 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.3 | 2.7 | 4.2 | 1.2 | 5.0 | 5.5 | ns |
| C_L = 15 pF | | | | | | | | | |
| t _{pd} | propagation delay | nA, nB to nY; see Figure 8 | [2] | | | | | | |
| | | V _{CC} = 0.8 V | - | 23.9 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 3.4 | 6.8 | 14.6 | 3.1 | 16.4 | 18.1 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 2.3 | 4.8 | 8.9 | 2.0 | 10.4 | 11.5 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.9 | 4.0 | 7.0 | 1.7 | 8.3 | 9.2 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.7 | 3.4 | 5.4 | 1.5 | 6.3 | 7.0 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.6 | 3.2 | 4.8 | 1.4 | 5.7 | 6.3 | ns |
| C_L = 30 pF | | | | | | | | | |
| t _{pd} | propagation delay | nA, nB to nY; see Figure 8 | [2] | | | | | | |
| | | V _{CC} = 0.8 V | - | 34.2 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.6 | 9.0 | 19.9 | 4.1 | 22.4 | 24.7 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 3.4 | 6.4 | 11.8 | 2.9 | 13.9 | 15.3 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 2.6 | 5.3 | 9.3 | 2.3 | 11.1 | 12.3 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 2.4 | 4.5 | 7.1 | 2.1 | 8.5 | 9.4 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.3 | 4.2 | 6.4 | 2.1 | 7.7 | 8.5 | ns |

Table 8. Dynamic characteristics ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol | Parameter | Conditions | T _{amb} = 25 °C | | | T _{amb} = -40 °C to +125 °C | | | Unit |
|---|-------------------------------|--|--------------------------|--------------------|-----|--------------------------------------|-------------|--------------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| C_L = 5 pF, 10 pF, 15 pF and 30 pF | | | | | | | | | |
| C _{PD} | power dissipation capacitance | f _i = 1 MHz; V _I = GND to V _{CC} | [3] | | | | | | |
| | | V _{CC} = 0.8 V | - | 2.6 | - | - | - | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | - | 2.7 | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | - | 2.8 | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | - | 2.9 | - | - | - | - | pF |
| | | V _{CC} = 2.3 V to 2.7 V | - | 3.3 | - | - | - | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | - | 3.8 | - | - | - | - | pF |

[1] All typical values are measured at nominal V_{CC}.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

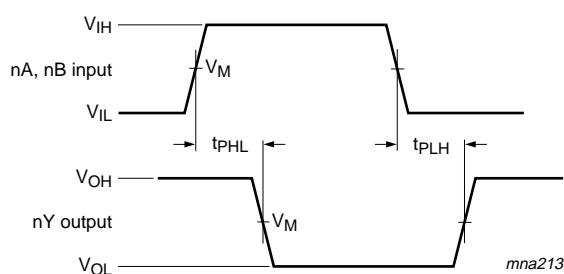
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;f_o = output frequency in MHz;C_L = output load capacitance in pF;V_{CC} = supply voltage in V;

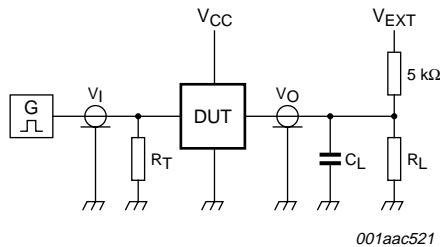
N = number of inputs switching;

$$\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$$

12. Waveforms

Measurement points are given in [Table 9](#).Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.**Fig 8. The data input (nA, nB) to output (nY) propagation delays****Table 9. Measurement points**

| Supply voltage | Output | Input | | |
|-----------------------------------|---|---|-----------------------------------|---|
| V _{CC} 0.8 V to 3.6 V | V _M 0.5 × V _{CC} | V _M 0.5 × V _{CC} | V _I V _{CC} | t _r = t _f ≤ 3.0 ns |



Test data is given in [Table 10](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 9. Load circuitry for switching times

Table 10. Test data

| Supply voltage | Load | | V_{EXT} | | |
|----------------|------------------------------|----------------------|--------------------|--------------------|--------------------|
| V_{CC} | C_L | R_L ^[1] | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | $2 \times V_{CC}$ |

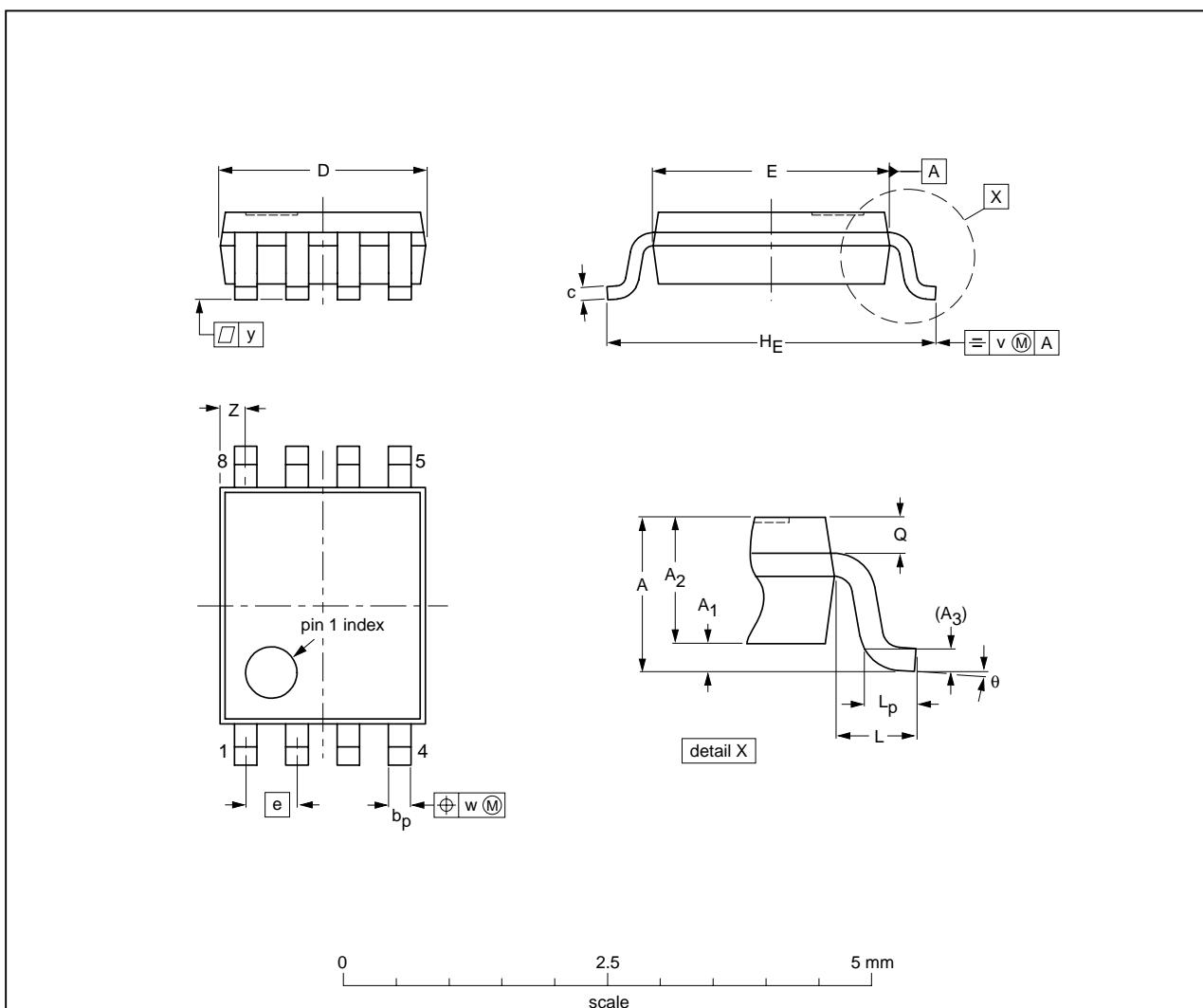
[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$.

For measuring propagation delays, set-up and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

13. Package outline

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽²⁾ | e | H _E | L | L _p | Q | v | w | y | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|-----|----------------|--------------|-----|------|-----|------------------|----------|
| mm | 1 0.00 | 0.15 0.60 | 0.85 0.12 | 0.12 | 0.27 0.17 | 0.23 0.08 | 2.1 1.9 | 2.4 2.2 | 0.5 | 3.2 3.0 | 0.4 | 0.40 0.15 | 0.21 0.19 | 0.2 | 0.13 | 0.1 | 0.4 0.1 | 8° 0° |

Notes

- Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-------|--|------------------------|------------|
| | IEC | JEDEC | JEITA | | | |
| SOT765-1 | | MO-187 | | | | 02-06-07 |

Fig 10. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body $1 \times 1.95 \times 0.5$ mm

SOT833-1

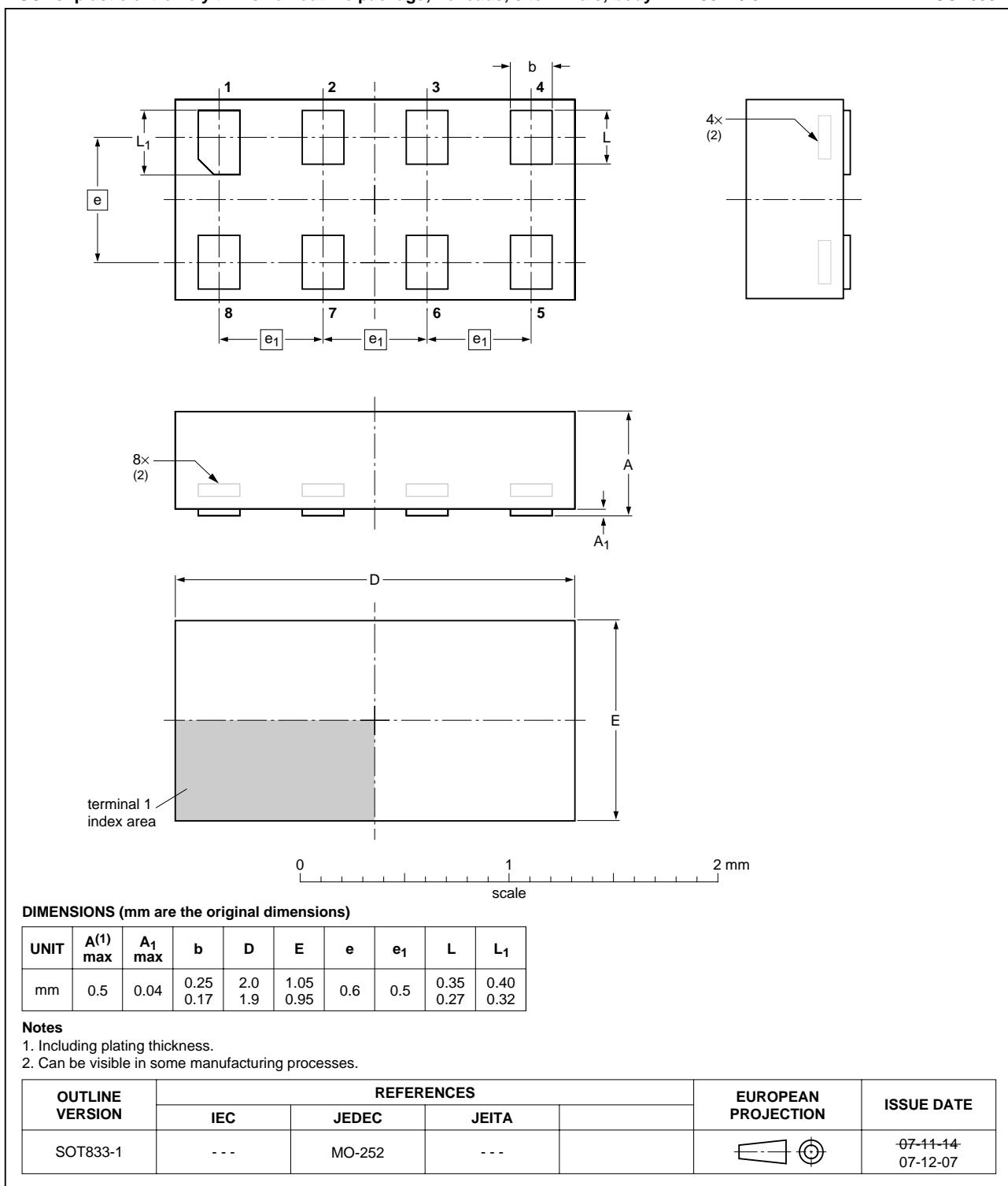


Fig 11. Package outline SOT833-1 (XSON8)

XSON8U: plastic extremely thin small outline package; no leads;
8 terminals; UTLP based; body $3 \times 2 \times 0.5$ mm

SOT996-2

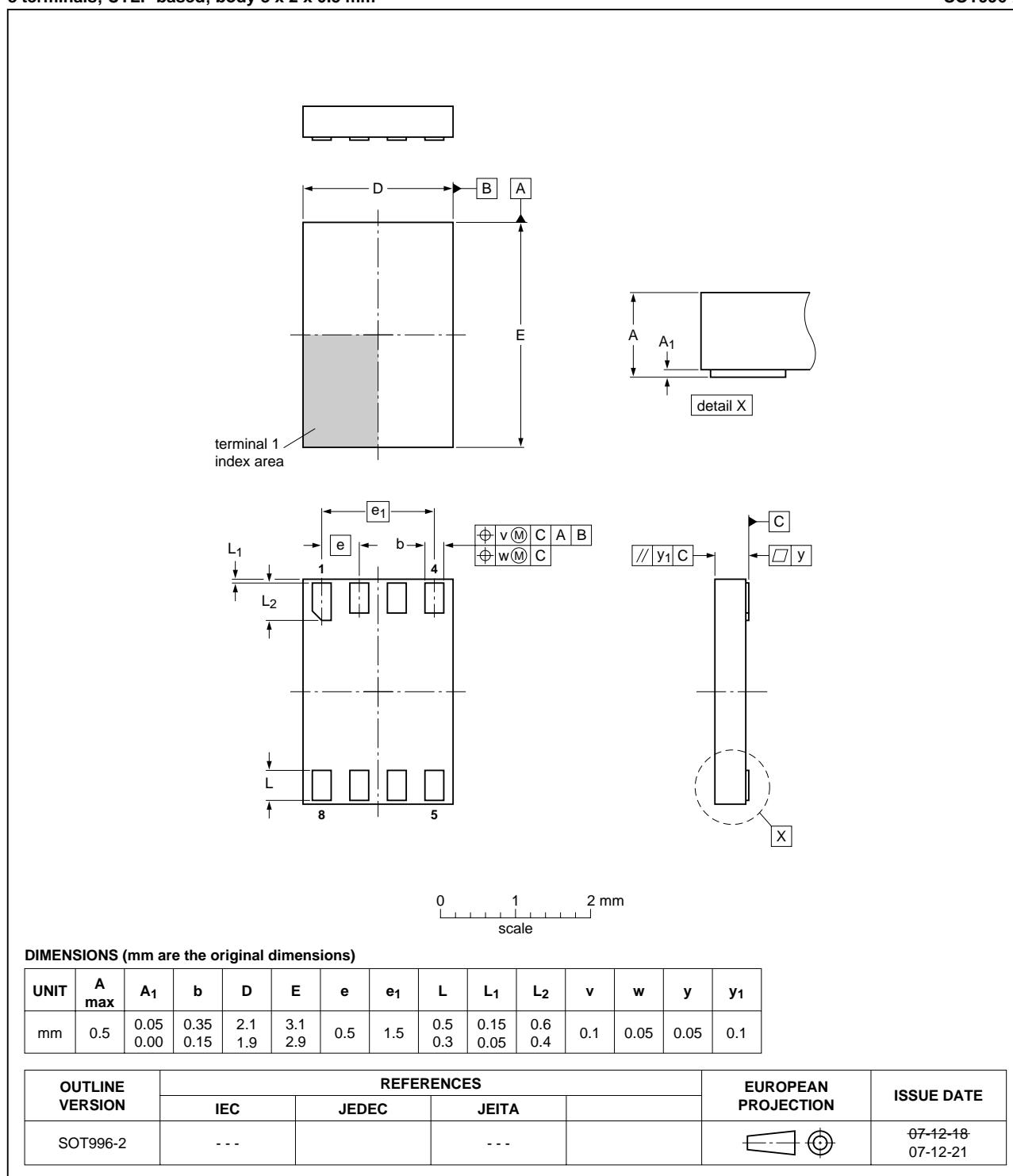


Fig 12. Package outline SOT996-2 (XSON8U)

XQFN8U: plastic extremely thin quad flat package; no leads;
8 terminals; UTLP based; body 1.6 x 1.6 x 0.5 mm

SOT902-1

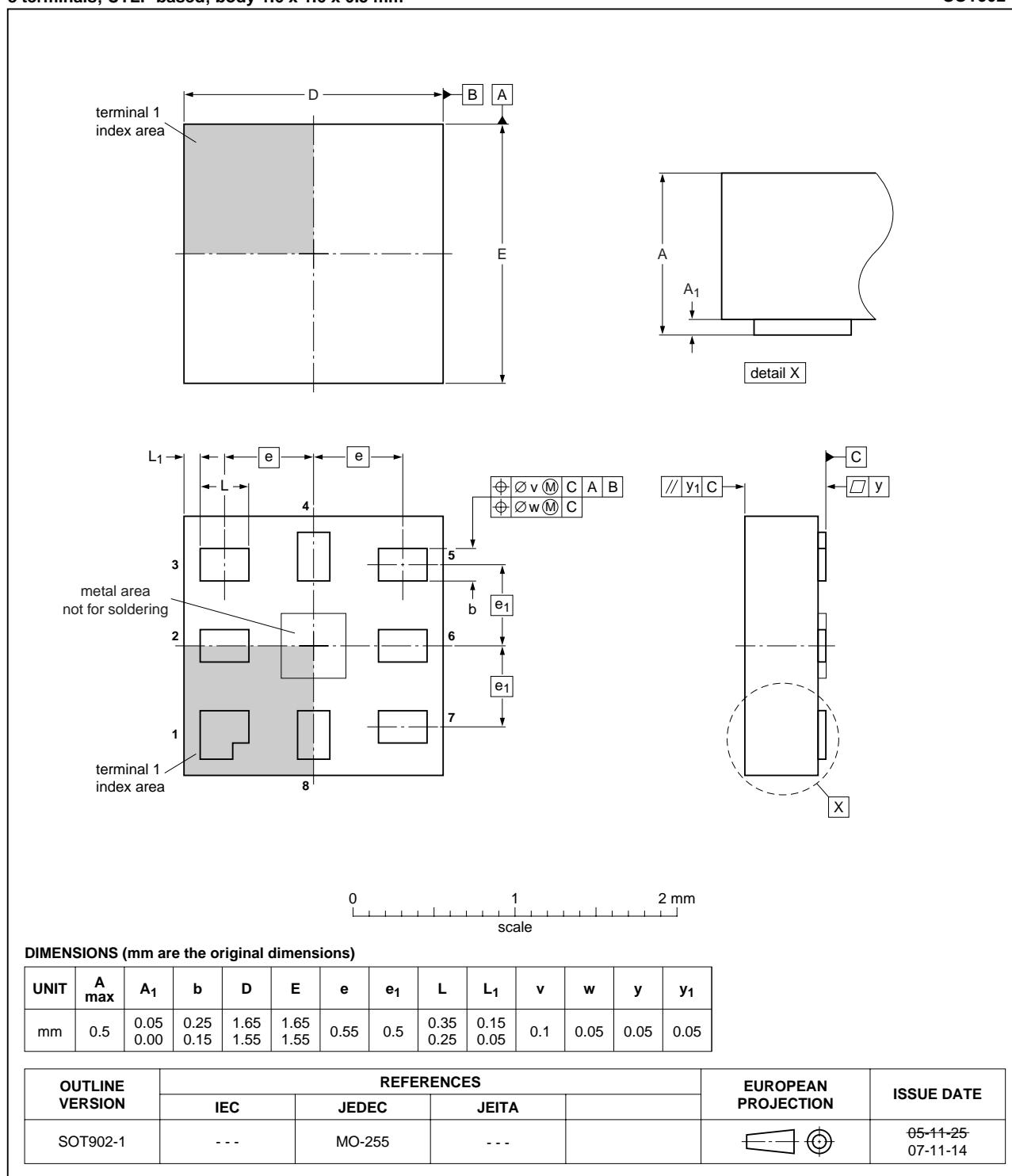


Fig 13. Package outline SOT902-1 (XQFN8U)

14. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|---|---------------|-------------|
| 74AUP2G02_3 | 20081211 | Product data sheet | - | 74AUP2G02_2 |
| Modifications: | | • Added type number 74AUP2G02GD (XSON8U package). | | |
| 74AUP2G02_2 | 20080319 | Product data sheet | - | 74AUP2G02_1 |
| 74AUP2G02_1 | 20060828 | Product data sheet | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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18. Contents

| | | |
|------|--|----|
| 1 | General description | 1 |
| 2 | Features | 1 |
| 3 | Ordering information | 2 |
| 4 | Marking | 2 |
| 5 | Functional diagram | 2 |
| 6 | Pinning information | 3 |
| 6.1 | Pinning | 3 |
| 6.2 | Pin description | 3 |
| 7 | Functional description | 4 |
| 8 | Limiting values | 4 |
| 9 | Recommended operating conditions | 4 |
| 10 | Static characteristics | 5 |
| 11 | Dynamic characteristics | 8 |
| 12 | Waveforms | 9 |
| 13 | Package outline | 11 |
| 14 | Abbreviations | 15 |
| 15 | Revision history | 15 |
| 16 | Legal information | 16 |
| 16.1 | Data sheet status | 16 |
| 16.2 | Definitions | 16 |
| 16.3 | Disclaimers | 16 |
| 16.4 | Trademarks | 16 |
| 17 | Contact information | 16 |
| 18 | Contents | 17 |

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